

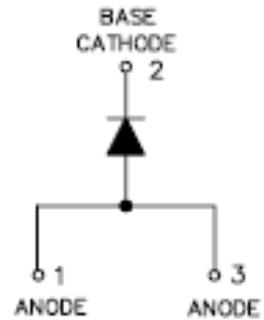
## MBRD360 THRU MBRD3200 SCHOTTKY RECTIFIER

**Applications:**

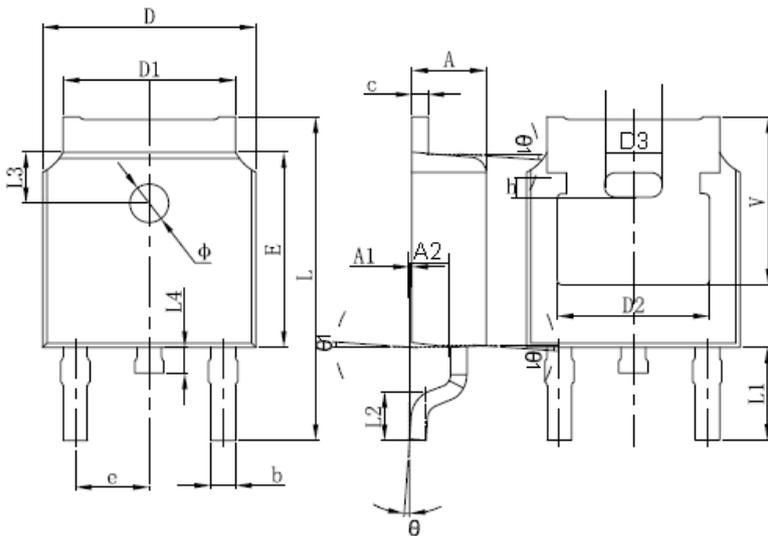
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

**Features:**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



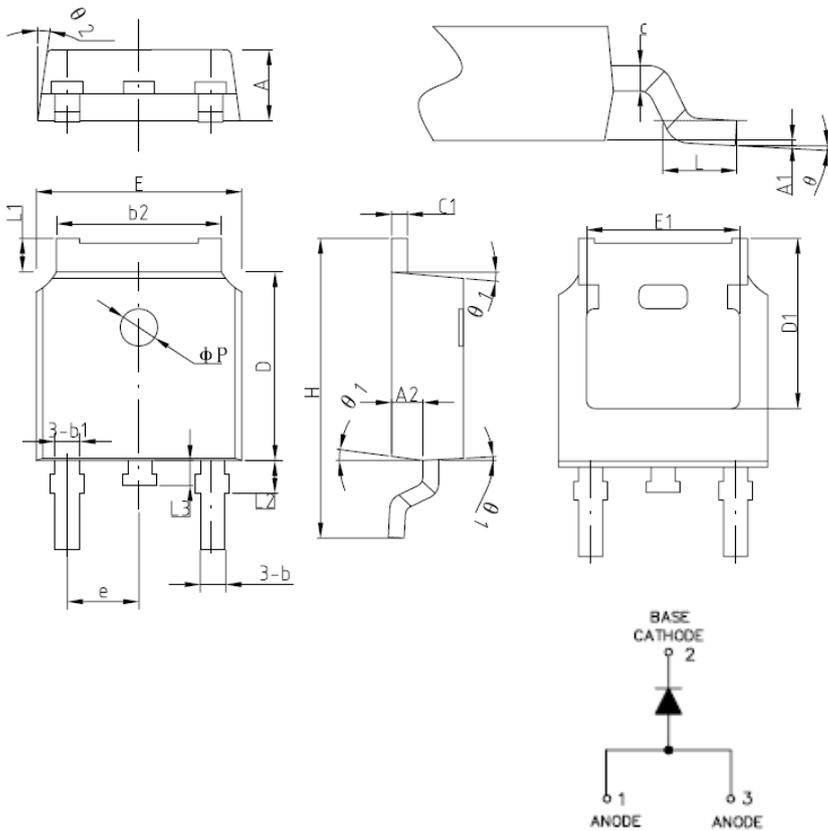
**Mechanical Dimensions: In mm/Inches**



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.380	0.087	0.094
A10.000	0.000	0.100	0.000	0.004
b	0.710	0.810	0.028	0.032
c	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
D2	4.830 REF.		0.190 REF.	
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
L3	1.600 REF.		0.063 REF.	
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
A2	0.910	1.110	0.036	0.044
V	5.350 REF.		0.211 REF.	
D3	1.778 REF.		0.070 REF.	
h	0.762 REF.		0.030 REF.	
θ1	7°		7°	

**OPTION 1(CJ)**

- China - Germany - Korea - Singapore - United States •
- <http://www.smc-diodes.com> - [sales@smc-diodes.com](mailto:sales@smc-diodes.com) •



SYMBOL	MIN.	TYP.	MAX.
<b>A</b>	2.20	2.30	2.38
<b>A1</b>	0	-	0.10
<b>A2</b>	0.90	1.01	1.10
<b>b</b>	0.71	0.76	0.86
<b>b1</b>		0.76	
<b>b2</b>	5.13	5.33	5.46
<b>c</b>	0.47	0.50	0.60
<b>c1</b>	0.47	0.50	0.60
<b>D</b>	6.0	6.10	6.20
<b>D1</b>	-	5.30	-
<b>E</b>	6.50	6.60	6.70
<b>E1</b>	-	4.80	-
<b>e</b>	2.286BSC		
<b>H</b>	9.70	10.10	10.40
<b>L</b>	1.40	1.50	1.70
<b>L1</b>	0.90	-	1.25
<b>L2</b>		1.05	
<b>L3</b>		0.8	
<b>ΦP</b>		1.2	
<b>Θ</b>	0°	-	8°
<b>Θ1</b>	5°	7°	9°
<b>Θ2</b>	5°	7°	9°

**OPTION 2(HD)**

**DPAK**



**MBRD360  
THRU  
MBRD3200**

**Technical Data**  
Data Sheet N0798, Rev. -

*Green Products*

**Marking Diagram:**



First row: Part Number (MBRD360, MBRD380, MBRD3100, MBRD3150, MBRD3200)  
Second row: SSG YYWWL  
YY is the manufacture year, WW is the manufacture week code, L is the wafer's Lot Number

**Ordering Information:**

Device	Package	Shipping
MBRD360 MBRD380 MBRD3100 MBRD3150 MBRD3200	DPAK (Pb-Free)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.



**MBRD360  
THRU  
MBRD3200**

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**Maximum Ratings and Electrical characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristics	Symbol	MBRD 360	MBRD 380	MBRD 3100	MBRD 3150	MBRD 3200	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	80	100	150	200	V
Average Forward Current	$I_{F(AV)}$	3					A
Max. Peak One Cycle Non-Repetitive Surge Current(8.3ms Single half sine- wave)	$I_{FSM}$	80					A
Max. Forward Voltage Drop* @3A, 25°C	$V_F$	0.65	0.75	0.85	0.90	0.92	V
Max. Reverse Current* @ $V_{RWM}$ , 25°C	$I_R$	1					mA
Max. Junction Capacitance(Note1)	$C_T$	250			100		pF
Junction Temperature	$T_J$	-55 to +150					°C
Storage Temperature	$T_{stg}$	-55 to +150					°C
Typical Thermal Resistance Junction to Case (DC operation)	$R_{\theta JC}$	6.0					°C/W
Approximate Weight	wt	0.39					g
Case Style		DPAK					

\* Pulse Width < 300 $\mu$ s, Duty Cycle <2%

Note1: Measured at 1.0 MHz and applied reverse voltage of 5.0V D.C.

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**MBRD360  
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**Technical Data  
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